

SANYO Semiconductors **DATA SHEET**

LV7150V— Switch for the Wideband Video Signal (with LPF)

Overview

The LV7150V is switch for the wideband video signal. It has the two input switches by three channels.

It built in the 6MHz/12MHz/30MHz-LPF. It is the best for the filter to remove the digital clock noise of the Y/Pb/Pr or RGB Analog video signal before the A/D converter.

It can correspond to the full HD signal because it provides the flat frequency response to 60MHz.

Functions

- Two input switches × three channels
- Y/Pb/Pr and RGB signal inputs
- Flat frequency response to 60MHz (Bypass filter)
- 6MHz/12MHz/30MHz-LPF

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		6	V
Allowable power dissipation	Pd max	Ta≤75°C Mounted on a specified board *	300	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +125	°C

Note *: Mounted on a specified board: 114.3mm×76.1mm×1.6mm glass epoxy

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Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		5	٧
Operating supply voltage Range	V _{CC} opg		4.75 to 5.25	V

Electrical Characteristics at Ta = 25°C, $V_{CC} = 5.0V$

	Inpu		Input	signal Out		Out	Total Octobries		Ratings		unit
Parameter	Input	Point	Signal	Freq	Mag	Point	Point Test Condition		typ	max	unit
V _{CC} supply curren	t & Internal re	eference re	gulator								
V _{CC} supply current		V3					At non-signal, The current flows to 3pin	26	34	42	mA
Internal reference regulator voltage						T16	The voltage of 16pin	2.8	3.0	3.2	٧
Voltage gain		•	•	•							
Voltage gain	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	100k	300mVpp	T15 T13 T11	Output gain for input	-0.5	-0.2	0.0	dB
Frequency respons	se										
response at LPF_Through Frequency	Py/Pb/Pr R/G/B Py/Pb/Pr	T1A T2A T4A T5A T7A T8A T1A T2A	SIG2	60M 100k 6M	300mVpp	T15 T13 T11 T15	LPF_Through is selected, Output gain difference between 100kHz and 60MHz 6MHz_LPF is selected,	-3.0	-1.0	1.0	dB
response 1 at 6MHz_LPF	R/G/B	T4A T5A T7A T8A	SIG2	100k	300mVpp	T13 T11	Output gain difference between 100kHz and 6MHz	-3.0	0.0	1.0	dB
Frequency response 2 at 6MHz _LPF	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	13.5M 100k	300mVpp	T15 T13 T11	6MHz_LPF is selected, Output gain difference between 100kHz and 13.5MHz		-30.0	-20.0	dB
Frequency response 1 at 12MHz_LPF	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	12M 100k	300mVpp	T15 T13 T11	12MHz_LPF is selected, Output gain difference between 100kHz and 12MHz	-3.0	0.0	1.0	dB
Frequency response 2 at 12MHz_LPF	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	27M 100k	300mVpp	T15 T13 T11	12MHz_LPF is selected, Output gain difference between 100kHz and 27MHz		-30.0	-20.0	dB
Frequency response 1 at 30MHz_LPF	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	20M 100k	300mVpp	T15 T13 T11	30MHz_LPF is selected, Output gain difference between 100kHz and 20MHz	-1.0	0.0	1.0	dB
Frequency response 2 at 30MHz_LPF	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	30M 100k	300mVpp	T15 T13 T11	30MHz_LPF is selected, Output gain difference between 100kHz and 30MHz	-3.5	-1.0	1.5	dB
Frequency response 3 at 30MHz_LPF	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	74M 100k	300mVpp	T15 T13 T11	30MHz_LPF is selected, Output gain difference between 100kHz and 74MHz		-45.0	-33.0	dB
S/N	S/N										
S/N ratio at 30MHz_LPF	Py R G B	T1A T2A T4A T5A T7A T8A	SIG1	30M 100k	650mVpp	T15 T13 T11	30MHz_LPF is selected, The S/N ratio from 100kHz to 30MHz		-60.0	-50.0	dB
Crosstalk											
Crosstalk	Py/Pb/Pr R/G/B	T1A T2A T4A T5A T7A T8A	SIG2	5M	700mVpp	T15 T13 T11	The ratio of the output leak of the non-selection input		-60.0	-55.0	dB

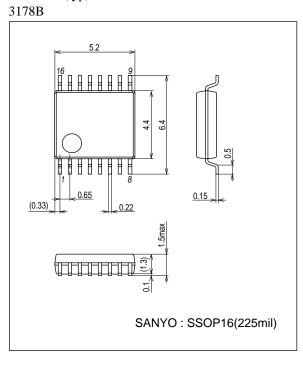
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D	lat		Input signal		Out	Test Condition	Ratings		14			
Parameter	Input	Point	Signal	Freq	Mag	Point	l est Condition	min	typ	max	unit	
Group delay	Group delay											
Group delay	Py/Pb/Pr	T1A T2A		COM		T15	LPF_Through is selected,					
at LPF_Through	R/G/B	T4A T5A	SIG2	SIG2 60M 300mVp	SIG2 1300mV	300mVpp	T13	Delay difference between		0.5	2.0	ns
	R/G/B	T7A T8A		100k		T11	100kHz and 60MHz					
Group delay	Py/Pb/Pr	T1A T2A		6M		T15	6MHz_LPF is selected,					
at 6MHz_LPF	R/G/B	T4A T5A S	SIG2		300mVpp	T13	Delay difference between		40.0	70.0	ns	
	K/G/B	T7A T8A		100k		T11	100kHz and 6MHz					
Group delay	Py/Pb/Pr	T1A T2A		12M		T15	12MHz_LPF is selected,					
at 12MHz_LPF	R/G/B	T4A T5A	SIG2	12W	300mVpp	T13	Delay difference between		20.0	40.0	ns	
	R/G/B	T7A T8A		TOOK		T11	100kHz and 12MHz					
Group delay	Du/Dh/Dr	T1A T2A		2014		T15	30MHz_LPF is selected,					
at 30MHz_LPF	Py/Pb/Pr R/G/B	T4A T5A	SIG2	30M 3	300mVpp	T13	Delay difference between		10.0	20.0	ns	
	K/G/B	T7A T8A		100k		T11	100kHz and 30MHz					

Package Dimensions

unit: mm (typ)



Pin Control Table

Pin Control Table

SW No.	Pin No.	SW function name
SW1	Pin12	CLAMP/BIAS_CTL
SW2	Pin10	Filter_CTL1
SW3	Pin9	Filter_CTL2
SW4	Pin14	Input_Select_CTL

Input Control Table

nput Control Tuble					
CLAMP/BIAS_CTL	Mode selected				
Low (0 to 0.7V)	CLAMP (Y/Pb/Pr_Mode)				
High (2.3V to V _{CC})	BIAS (RGB_Mode)				

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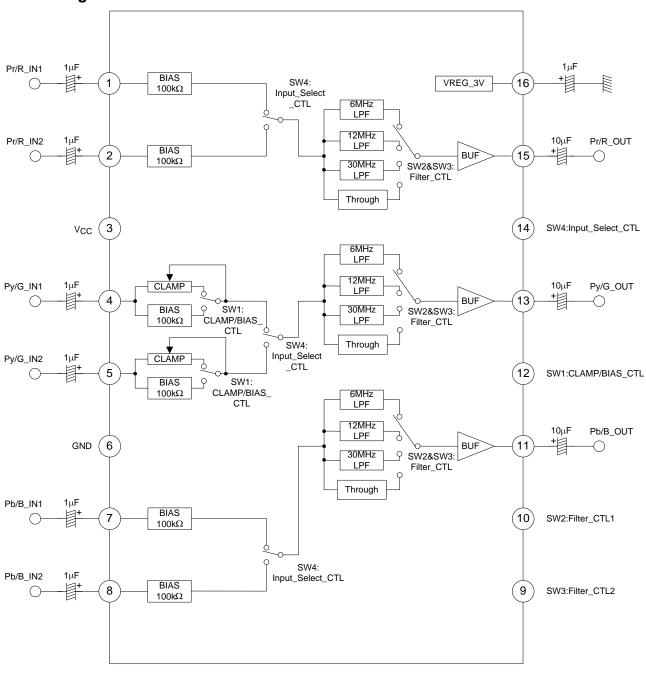
Filter Control Table

Filter_CTL1	Filter_CTL2	Mode selected
Low (0 to 0.7V)	Low (0 to 0.7V)	6Mz_LPF
Low (0 to 0.7V)	High (2.3V to V _{CC})	12Mz_LPF
High (2.3V to V _{CC})	Low (0 to 0.7V)	30Mz_LPF
High (2.3V to V _{CC})	High (2.3V to V _{CC})	LPF_Through

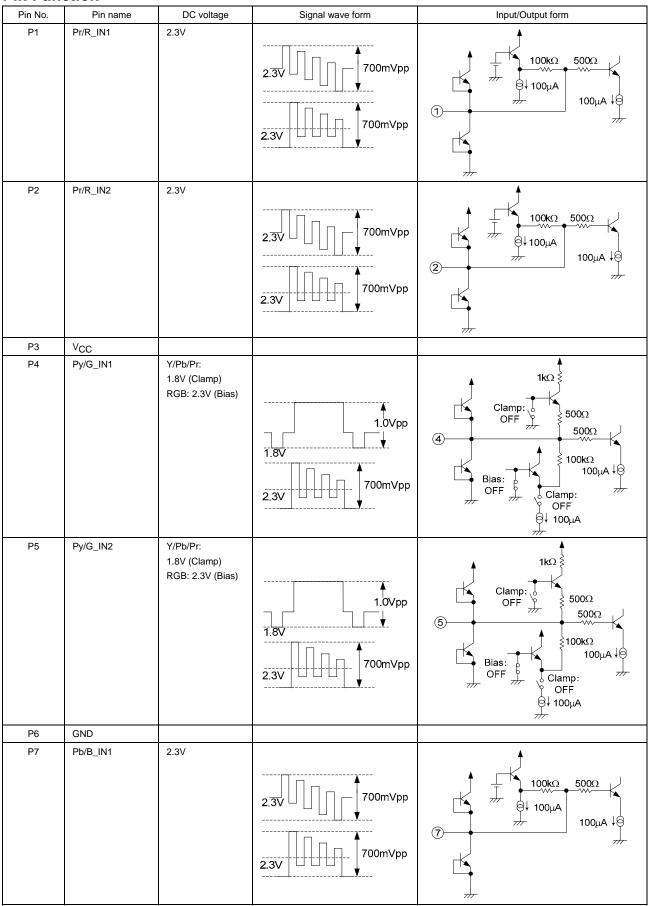
Input Select Control Table

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Input_Select_CTL	Mode selected
Low (0 to 0.7V)	CH1_select
High (2.3V to V _{CC})	CH2_select

Block Diagram



Pin Function



Continued from preceding page.

Pin No.	m preceding page. Pin name	DC voltage	Signal wave form	Input/Output form
P8	Pb/RB_IN2	2.3V	2.3V 700mVpp 700mVpp 700mVpp	100kΩ 500Ω
P9	Filter_CTL2	High: 2.3 to V _{CC} Low: 0 to 0.7V		9 10kΩ π
P10	Filter_CTL1	High: 2.3 to V _{CC} Low: 0 to 0.7V		10kΩ 50kΩ m
P11	Pb/B_OUT	2.3V	2.3V 700mVpp 2.3V 700mVpp	200Ω 50Ω 200Ω 200Ω
P12	CLP/BIAS_CTL	High: 2.3 to V _{CC} RGB (Bias) Low: 0 to 0.7V Y/Pb/Pr (Clamp)		10kΩ 10kΩ 50kΩ ///
P13	Py/G_OUT	Y/Pb/Pr: 1.8V (Clamp) RGB: 2.3V (Bias)	1.0Vpp 1.8V 700mVpp	200Ω \$ 50Ω 13 200Ω \$

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Pin No.	Pin name	DC voltage	Signal wave form	Input/Output form
P14	Input_Select_CTL	High: 2.3 to V _{CC} Ch2 Low: 0 to 0.7V Ch1		10kΩ 10kΩ 50kΩ ///
P15	Pr/R_OUT	2.3V	2.3V 700mVpp 2.3V 700mVpp	200Ω \$ 50Ω 15
P16	REG3V	3.0V		200Ω \$ 100Ω \$ 100Ω \$ 100Ω \$ 40kΩ \$ 25kΩ \$ 100Ω \$ 1

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